

Description

The AR0532S2 is a uni-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive high-speed data lines. The AR0532S2 has an ultra-low capacitance with a typical value at 1pF, and complies with the IEC 61000-4-2 (ESD) standard with $\pm 25\text{kV}$ air and $\pm 20\text{kV}$ contact discharge. It is assembled into a lead-free SOT-23 package. The small size, ultra-low capacitance and high ESD surge protection make AR0532S2 an ideal choice to protect cell phone, digital visual interfaces and other high speed ports.

Features

- Low capacitance: 1pF typical
- Ultra low leakage: nA level
- Operating voltage: 5V
- Low clamping voltage
- Up to 2-line protects
- Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 - Air discharge: $\pm 25\text{kV}$
 - Contact discharge: $\pm 20\text{kV}$
 - IEC61000-4-5 (Lightning) 12A (8/20 μs)
- RoHS Compliant

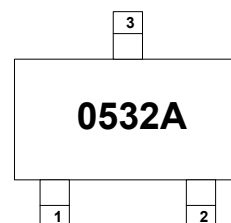
Mechanical Characteristics

- Package: SOT-23
- Lead Finish: Matte Tin
- Case Material: “Green” Molding Compound.
- Terminal Connections: See Diagram Below
- Marking Information: See Below

Applications

- Cellular Handsets and Accessories
- Display Ports
- MDDI Ports
- USB 2.0 and 3.0 Ports
- HDMI 1.3 and 1.4
- Digital Visual Interface (DVI)
- PCI Express and Serial SATA Ports
- Notebook Computer

Marking Information

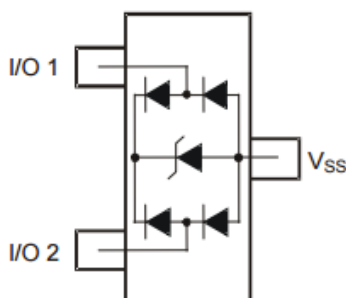


0532A = Device Marking Code

Ordering Information

Part Number	Packaging	Reel Size
AR0532S2	3000/Tape & Reel	7 inch

Dimensions and Pin Configuration



Pin Schematic

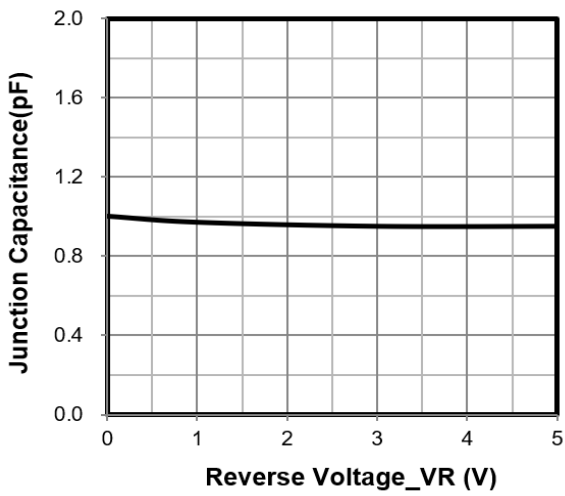
Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	Ppk	300	W
Peak Pulse Current (8/20μs)	I _{PP}	12	A
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	V _{ESD}	±25 ±20	kV
Operating Temperature Range	T _J	-55 to +125	°C
Storage Temperature Range	T _{stg}	-55 to +150	°C

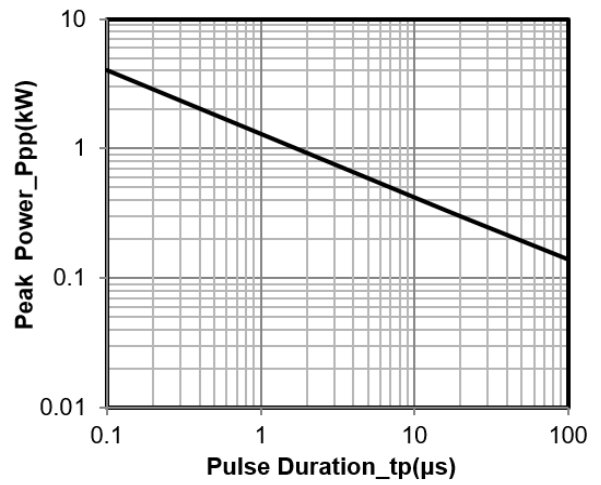
Electrical Characteristics (T_A=25°C unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V _{RWM}			5	V	
Breakdown Voltage	V _{BR}	6			V	I _T = 1mA, pin 1 or pin 2 to pin 3
Reverse Leakage Current	I _R			0.5	μA	V _{RWM} = 5V, Pin 1 or pin 2 to pin 3
Clamping Voltage	V _C			9	V	I _{PP} = 1A (8 x 20μs pulse), pin 1 or pin 2 to pin 3
Clamping Voltage	V _C			25	V	I _{PP} = 12A (8 x 20μs pulse), pin 1 or pin 2 to pin 3
Junction Capacitance	C _J		1		pF	V _R = 0V, f = 1MHz, pin 1 or pin 2 to pin 3

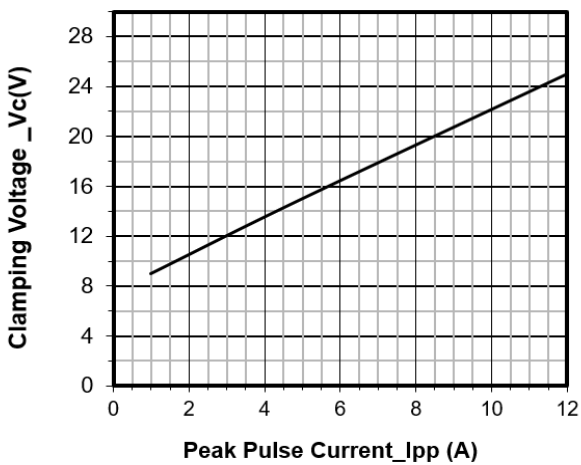
Typical Performance Characteristics (TA=25°C unless otherwise Specified)



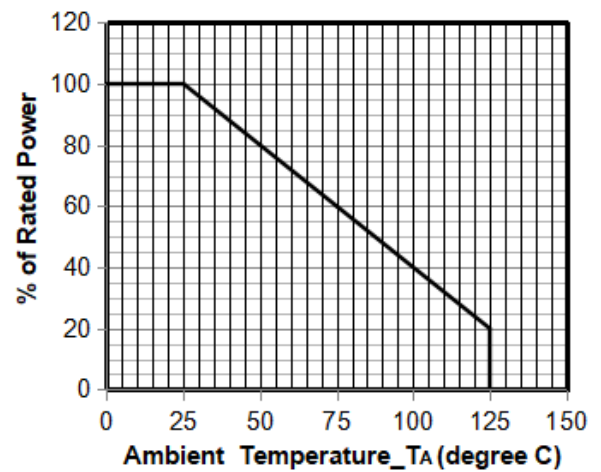
Junction Capacitance vs. Reverse Voltage



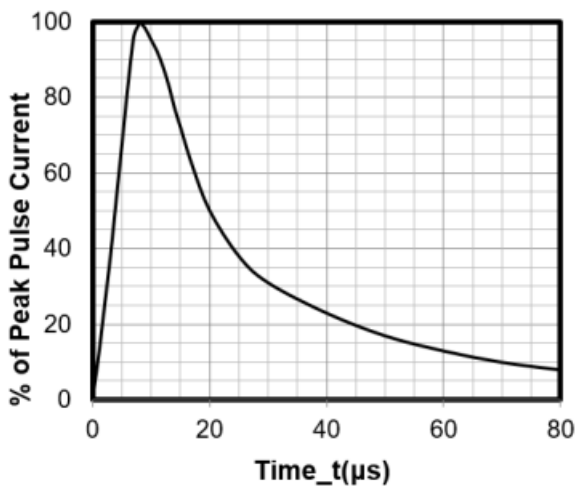
Peak Pulse Power vs. Pulse Time



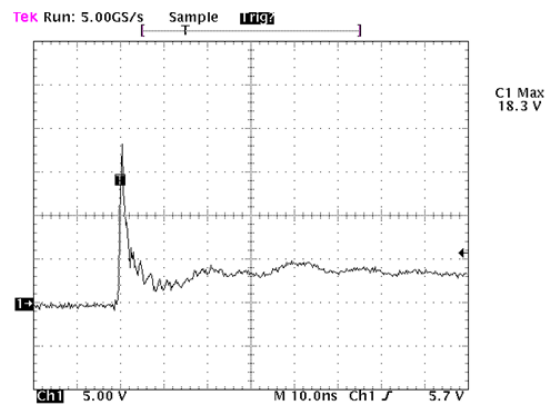
Clamping Voltage vs. Peak Pulse Current



Power Derating Curve



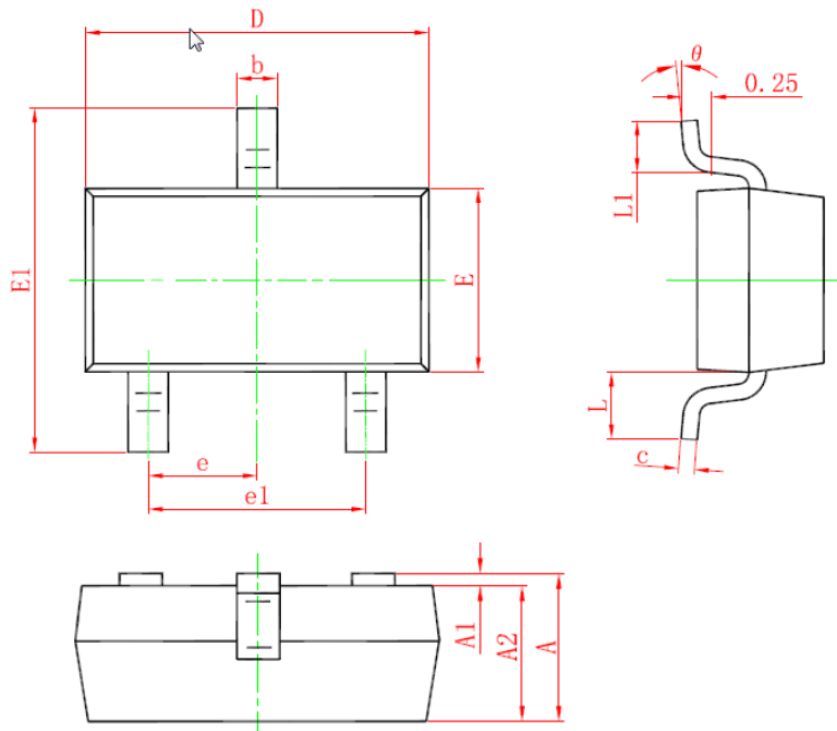
8 X 20μs Pulse Waveform



Note: Data is taken with a 10x attenuator

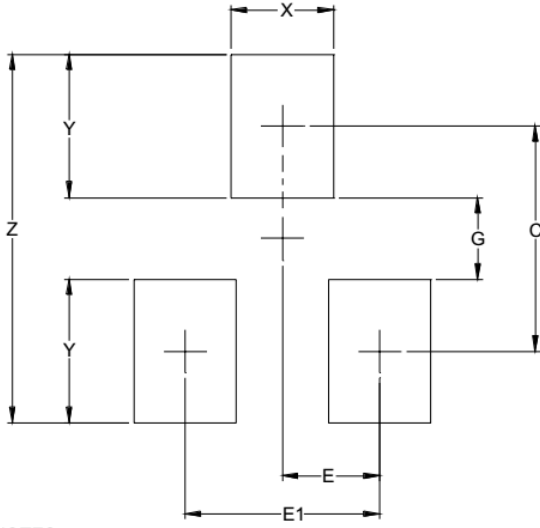
ESD Clamping Voltage

8 kV Contact per IEC61000-4-2

SOT-23 Package Outline Drawing


SYM	DIMENSIONS					
	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.90	--	1.15	0.035	--	0.045
A1	0.00	--	0.10	0.000	--	0.004
A2	0.90	--	1.05	0.035	--	0.041
b	0.30	--	0.50	0.012	--	0.020
c	0.08	--	0.15	0.003	--	0.006
D	2.80	--	3.00	0.110	--	0.118
E	1.20	--	1.40	0.047	--	0.055
E1	2.25	--	2.55	0.089		0.100
e	0.95TYP			0.037TYP		
e1	1.80	--	2.00	0.071	--	0.079
L	0.55REF			0.022REF		
L1	0.30	--	0.50	0.012	--	0.020
θ	0°	--	8°	0°	--	8°

Suggested Land Pattern



SYM	DIMENSIONS	
	INCHES	MILLIMETERS
C	(.087)	(2.20)
E	.037	0.95
E1	.075	1.90
G	.031	0.80
X	.039	1.00
Y	.055	1.40
Z	.141	3.60

Contact Information

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